What is claimed is:

 A RF oscillator apparatus comprising:
 a conductor plate supporting a dielectric resonator and a microwave monolithic integrated circuit chip which is electromagnetically coupled to the dielectric resonator; and

a conductive wall which determines a resonance frequency of the dielectric resonator.

wherein the microwave monolithic integrated circuit chip and the dielectric resonator are provided on the same conductor plate.

- A RF oscillator apparatus according to claim 1, wherein an air gap is formed between the dielectric resonator and the conductor plate.
- 3. A RF oscillator apparatus according to claim 1, wherein the dielectric resonator is supported by a dielectric supporter such that an air gap is formed between the dielectric resonator and the conductor plate.
- 4. ARF oscillator apparatus according to claim 3, wherein the dielectric supporter has such a shape as to straddle both sides of the dielectric resonator, and is fixed on the conductor plate at the both sides of the dielectric resonator, and wherein the dielectric supporter and a portion of an upper portion of the dielectric resonator are jointed to each other.
- ARP oscillator apparatus according to claim 1, wherein the conductive wall covers an upper portion of the dielectric resonator.
 - 6. A RF oscillator according to claim 1, 2, 3, 4 or 5,

wherein a chip capacitor connected to the microwave monolithic integrated circuit chip is loaded on the conductor plate.

- 7. A transceiver apparatus comprising:
- a RF oscillator apparatus having a conductor plate which supports a dielectric resonator, a microwave monolithic integrated circuit chip which is electromagnetically coupled to the dielectric resonator, and a conductive wall which determines a resonance frequency of the dielectric resonator;
- a receiving section which makes a RF signal generated from the RF oscillator apparatus a local oscillation signal of a mixer; and
- a transmitting section having an amplifier for amplifying power. $% \begin{center} \begin{cente$
- 8. A transceiver apparatus according to claim 7, wherein the RF oscillator apparatus whose the resonance frequency is set in advance is built into the transceiver apparatus.
- 9. A transceiver apparatus according to claim 7, wherein such a seal material as to cover an upper portion of the conductive wall is provided.
- 10. A transceiver apparatus according to claim 7, wherein the receiving section and the amplifier are constituted by microwave monolithic integrated circuit chips.
- 11. A transceiver apparatus comprising:
 a RF oscillator apparatus having a cavity resonator and a
 conductor plate which supports a microwave monolithic
 integrated circuit chip electromagnetically coupled to the
 cavity resonator, a resonance frequency of the cavity resonator

being set in advance;

a receiving section which makes a RF signal generated from the RF oscillator apparatus a local oscillation signal of a mixer; and

a transmitting section having an amplifier for amplifying power.

- 12. A RF oscillator according to claim 2, wherein a chip capacitor connected to the microwave monolithic integrated circuit chip is loaded on the conductor plate.
- 13. A RF oscillator according to claim 3, wherein a chip capacitor connected to the microwave monolithic integrated circuit chip is loaded on the conductor plate.
- 14. A RF oscillator according to claim 4, wherein a chip capacitor connected to the microwave monolithic integrated circuit chip is loaded on the conductor plate.
- 15. A RF oscillator according to claim 5, wherein a chip capacitor connected to the microwave monolithic integrated circuit chip is loaded on the conductor plate.
- 16. A transceiver apparatus according to claim 8, wherein such a seal material as to cover an upper portion of the conductive wall is provided.
- 17. A transceiver apparatus according to claim 8, wherein the receiving section and the amplifier are constituted by microwave monolithic integrated circuit chips.
- 18. A transceiver apparatus according to claim 9, wherein the receiving section and the amplifier are constituted by microwave monolithic integrated circuit chips.

- 19. A transceiver apparatus according to claim 16, wherein the receiving section and the amplifier are constituted by microwave monolithic integrated circuit chips.
- 20. A manufacturing process of a transceiver apparatus, the process comprising the steps of:

preparing a RF oscillator apparatus whose resonance frequency is set in advance, a first semiconductor chip constituting a receiving section which makes a RF signal generated from the RF oscillator apparatus a local oscillation signal of a mixer, and a second semiconductor chip constituting a transmitting section having an amplifier for amplifying power;

fixing the RF oscillator apparatus and the first and second semiconductor chips to a module substrate by an adhesive;

connecting wires of the module substrate to the RF oscillator apparatus and the first and second semiconductor chips by wire bonding, respectively; and

airtightly sealing the RF oscillator apparatus and the first and second semiconductor chips loaded on the module substrate.

- 21. A manufacturing process of a transceiver apparatus according to claim 20, wherein the module substrate is used as a module substrate having a wiring substrate being connected by the wire bonding and a base substrate supporting the wiring substrate.
- 22. A manufacturing process of a transceiver apparatus according to claim 20, wherein the RF oscillator apparatus is

used as a RF oscillator apparatus having a dielectric resonator, a conductor plate which supports a microwave monolithic integrated circuit chip electromagnetically coupled to the dielectric resonator, and a conductive wall which determines a resonance frequency of the dielectric resonator.

- 23. A manufacturing process of a transceiver apparatus according to claim 20, wherein silver paste is used as the adhesive.
- 24. A manufacturing process of a transceiver apparatus according to claim 21, wherein the RF oscillator apparatus is used as a RF oscillator apparatus having a dielectric resonator, a conductor plate which supports a microwave monolithic integrated circuit chip electromagnetically coupled to the dielectric resonator, and a conductive wall which determines a resonance frequency of the dielectric resonator.
- 25. A manufacturing process of a transceiver apparatus according to claim 21, wherein silver paste is used as the adhesive.
- 26. A manufacturing process of a transceiver apparatus according to claim 22, wherein silver paste is used as the adhesive.
- 27. A manufacturing process of a transceiver apparatus according to claim 24, wherein silver paste 1s used as the adhesive.